








	FQU8P10TU	
	Hersteller-Teilenummer:	FQU8P10TU
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET P-CH 100V 6.6A IPAK
<p>Image may be representation. See specs for product details.</p>	Datenblätter:	 FQU8P10TU.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 4610 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	FQU8P10TU
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 100V 6.6A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	4610 pcs Stock
detaillierte Beschreibung	P-Channel 100V 6.6A (Tc) 2.5W (Ta), 44W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-PAK
Verlustleistung (max)	2.5W (Ta), 44W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6.6A (Tc)
Rds On (Max) @ Id, Vgs	530 mOhm @ 3.3A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	470pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































FQU8P10TU ist neu im Original, Suche FQU8P10TU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQU8P10TU AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQU8P10TU: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQU8P10 Original FQU8P10 Original</p>	 <p>FQU8P10TU Fairchild/ON Semiconductor MOSFET P-CH 100V 6.6A IPAK</p>	 <p>FQU7P20TU_AM002 AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 5.7A IPAK</p>	 <p>FQU9N25 FAIRCHI FQU9N25 FAIRCHI</p>
 <p>FQU9N25TU Fairchild/ON Semiconductor MOSFET N-CH 250V 7.4A IPAK</p>	 <p>FQU8N25TU Fairchild/ON Semiconductor MOSFET N-CH 250V 6.2A IPAK</p>	 <p>FQU9N25TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 7.4A IPAK</p>	 <p>FQU900N60Z FAIRCHI FAIRCHI TO-251</p>

heiße Teile

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Contact us: Info@Y-IC.com

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